25K1308, 25K1308A

Silicon N-Channel Power F-MOS FET

■ Features

- Low $R_{RD \text{ (on)}} = 0.9\Omega \text{ (typ.)}$
- High speed switching t_f=50ns (typ.)
- · No secondary breakdown
- High breakdown voltage

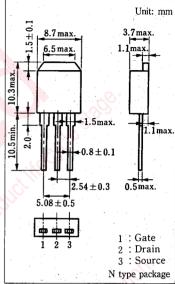
■ Use

- Non-contact relay.
- Motor control.
- Measuring Equipment.
- · Switching regulator.
- · Solenoid drive.

■ Absolute Maximum Ratings (Tc=25°C)

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Item		Symbol	Value	Unit	
Drain-source voltage	2SK1308	V	400	V	
	2SK1308A	V_{DSS}	450	, v	
Gate-source voltage	V _{GSS}	±20	v.O		
Drain current	DC	I_{D}	5	A	
	Peak-to-peak value	I_{DP}	10		
Power dissipation	Tc=25℃	P_{D}	40	W	
	Ta=25℃	I D	1.3		
Channel temperature		T_{ch}	150	C C	
Storage temperature		T _{stg}	$-55 \sim +150$	Ç	

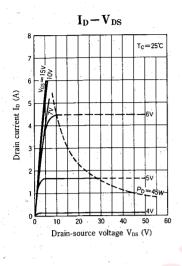
■ Package Dimensions

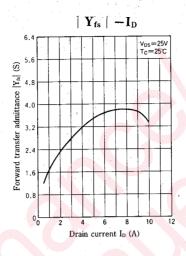


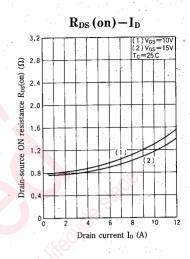
*Surface-mount type is also available. (Refer to p.82.)

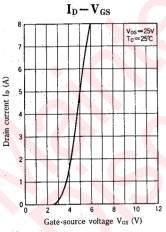
■ Electrical Characteristics (Tc=25°C)

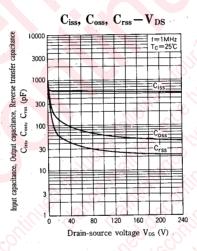
Item	Symbol	Condition	min.	typ.	max.	Unit
Drain current	I _{DSS}	$V_{DS} = 320V, V_{GS} = 0$	0		0.1	mA
Gate-source current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0$			±1	μA
Drain-source voltage 2SK1308 2SK1308A	$V_{ m DSS}$	$I_D = 1 \text{ mA}, V_{GS} = 0$	400			v
			450			
Gate threshold voltage	V _{th}	$V_{DS}=25V$, $I_D=1mA$	1		5	V
Drain-source ON resistance	R _{DS} (on)	$V_{GS}=10V$, $I_D=3A$		0.9	1.4 ·	Ω
Forward transfer admittance	Yfs	$V_{DS} = 25V$, $I_D = 3A$	1.8	3.0		S
Input capacitance	Ciss	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$		600		pF
Output capacitance	Coss			140		pF
Reverse transfer capacitance	C_{rss}			60		pF
Turn-on time	ton			40		ns
Fall time	t _f	$V_{GS} = 10V, I_D = 3A$ $V_{DS} = 150V, R_L = 50 \Omega$		50		ns
Delay time	t d (off)	. D3 - 100 - , 12L - 00		120		ns

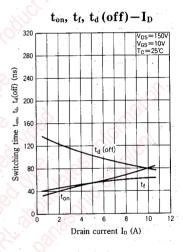


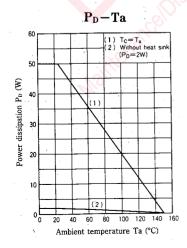


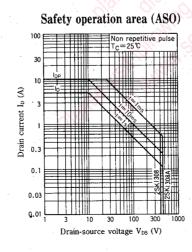


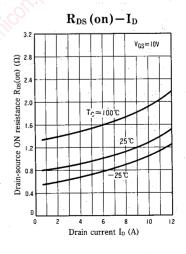












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